NSN 5961-00-105-7655

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-105-7655 **Inclosure Material:** Glass **Overall Length:** Between 0.734 inches and 0.766 inches **Terminal Length:** 0.147 inches **Overall Diameter:** Between 0.215 inches and 0.220 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 0.80 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 1.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius ambient air **Special Features:** 6.75 ghz test frequency; 2.0 ghz to 12.4 ghz frequency range **Test Data Document:** 81349-mil-c-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin **Specification Data:** 81349-mil-s-19500/362 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No